NSN 5961-01-230-2970

Transistor - Page 1 of 1

Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-230-2970 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.450 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case and mounting hardware **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 150.0 collector to base voltage/static/emitter open and 130.0 collector-to-emitter substaining voltage, resistance between base and emitter and 110.0 collector-to-emitter, substaining voltage, base open-circuited and 7.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 15.00 amperes source cutoff current and 5.00 amperes source cutoff current **Power Rating Per Characteristic:** 140.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No